Supplementary Material for: Switching the moiré lattice models in the twisted bilayer WSe₂ by strain or pressure

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1 Computational methods

The first-principles calculations are performed within the density functional theory (DFT) framework using the projected augmented-wave (PAW) method¹ as implemented in the Vienna ab initio simulation package (VASP).^{2,3} The exchange-correlation term is treated in the generalized gradient approximation (GGA) of Perdew-Burke-Ernzerhof (PBE).⁴ The Kohn-Sham orbitals are expanded in a plane wave basis set with an energy cutoff of 550 eV. The $15 \times 15 \times 1$ k-point grid and the Γ point are used for the ground state and relaxation calculations of the 1×1 unitcell and moiré supercell, respectively. All the structures are optimized until the Hellman-Feynman forces on each atom are smaller than $0.01 \text{ eV}/\text{\AA}$ and the energy convergence is reached when the energy difference is below 10^{-6} eV between two consecutive self-consistent steps. A vacuum space of more than 15 Å along the z direction is added to decouple artificial interactions between periodic neighboring slabs. Van der Waals corrections are taken into account using the Tkatchenko-Scheffler method. 5 The VESTA 6 package is used to visualize the geometry structures and the real space illustration of the wave functions. The real space illustrations of wave functions are constructed with pseudoatomic orbital using the first-principles calculation package OpenMX. Where the norm-conserving pseudo-potentials are used for the discretion of the core electron.^{7,8} The twisted bilayer WSe₂ supercells with twist angles of $5.1^{\circ}/54.9^{\circ}$, 4.4° , and 3.9° are generated along [2, -1] to obtain the minimal cells and contain 762, 1014, and 1302 atoms, respectively. A negligible tensile strain ($\approx 0.0013\%$) is applied on the hBN layers (the fully relaxed lattice constant is 2.509Å) to satisfy the commensurate periodic boundary condition in the ABA sandwich stacking heterostructure.



2 Squared wave function distribution of $t5.1^{\circ}$ WSe₂

Figure S1: Real space illustration of the squared wave functions $|\psi_k|^2$ of Γ (upper panel) and K valleys (lower panel) at γ for t5.1° WSe₂.

3 Untwisted bilayers



Figure S2: Left panel: the band structure of AA(upper) and AB(lower) stacked bilayer WSe₂ with orbital projections. The color description is the same as the main text; Right panel: Side views of the squared wave functions $|\psi_k|^2$ at Γ and K points in the order of increasing energy from left to right.

4 Band structures of other twisted angles



Figure S3: The DFT calculated band structures of twisted bilayer WSe_2 near Fermi level with different twisted angles (54.9°, 4.4° and 3.9°, from left to right, respectively).

5 5.1° tWSe₂ under out-of-plane pressure with/without BN layers

The pressure is calculated by:

$$p = \frac{\sum f_{z-BN_{top}} - f_{z-BN_{bottom}}}{2|\vec{a} \times \vec{b}|} \tag{1}$$

where f_z describes the calculated atomic force on each atom in the top/bottom layer after geometric relaxation. It turns out that:

Table S1: Calculated results for out-of-plane pressure for different initial layer distance d.

d (Å)	Pressure (GPa)
2.5	7.935
3	2.175
3.5	-0.562

To reduce computational cost, we remove the BN layers after relaxation and calculate the band structure. To exclude unexpected interactions between BN layers and tWSe₂, the density of states projected on BN layers and the tWSe₂ is plotted in Fig. S4(a). There seems no contribution of BN layers near the Fermi level. Besides, the band structure with BN layers is also similar to that without BN layers, as shown in Fig. S4(b).



Figure S4: (a) Projected density of states of BN-tWSe₂-BN sandwiched structure. (b) The band structure with and without BN layers, as plotted with red circles and blue lines, respectively.

References

- (1) Blöchl, P. E. Projector augmented-wave method. Phys. Rev. B 1994, 50, 17953–17979.
- (2) Kresse, G.; Furthmüller, J. Efficiency of ab-initio total energy calculations for metals and semiconductors using a plane-wave basis set. *Computational Materials Science* 1996, 6, 15–50.
- (3) Kresse, G.; Furthmüller, J. Efficient iterative schemes for ab initio total-energy calculations using a plane-wave basis set. *Phys. Rev. B* 1996, 54, 11169–11186.
- (4) Perdew, J. P.; Burke, K.; Ernzerhof, M. Generalized Gradient Approximation Made Simple. Phys. Rev. Lett. 1996, 77, 3865–3868.
- (5) Tkatchenko, A.; Scheffler, M. Accurate Molecular Van Der Waals Interactions from Ground-State Electron Density and Free-Atom Reference Data. *Phys. Rev. Lett.* 2009, 102, 073005.
- (6) Momma, K.; Izumi, F. VESTA3 for three-dimensional visualization of crystal, volumetric and morphology data. Journal of Applied Crystallography 2011, 44, 1272–1276.
- (7) Ozaki, T.; Kino, H. Numerical atomic basis orbitals from H to Kr. Phys. Rev. B 2004, 69, 195113.
- (8) Ozaki, T. Variationally optimized atomic orbitals for large-scale electronic structures. *Phys. Rev. B* 2003, 67, 155108.